



DTA123E

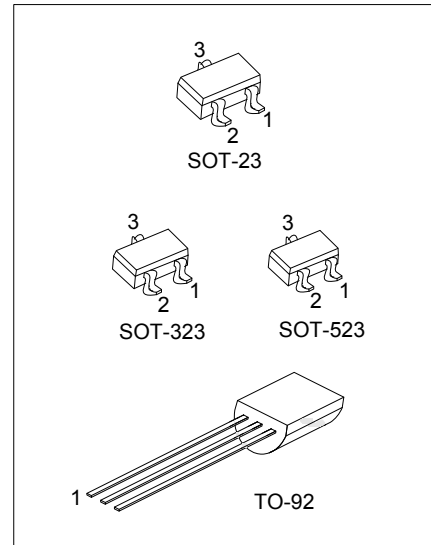
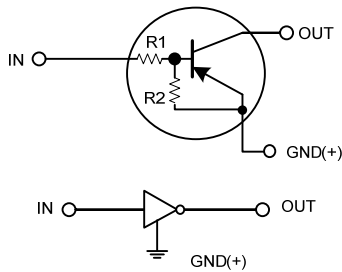
PNP SILICON TRANSISTOR

DIGITAL TRANSISTORS (BUILT-IN BIAS RESISTORS)

■ FEATURES

- * Built-in bias resistors that implies easy ON/OFF applications.
- * The bias resistors are thin-film resistors with complete isolation to allow positive input.

■ EQUIVALENT CIRCUIT

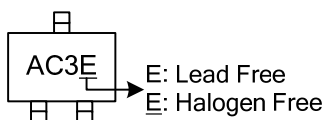


■ ORDERING INFORMATION

Order Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
DTA123EL-AE3-R	DTA123EG-AE3-R	SOT-23	G	I	O	Tape Reel
DTA123EL-AL3-R	DTA123EG-AL3-R	SOT-323	G	I	O	Tape Reel
DTA123EL-AN3-R	DTA123EG-AN3-R	SOT-523	G	I	O	Tape Reel
DTA123EL-T92-K	DTA123EG-T92-K	TO-92	G	O	I	Bulk
DTA123EL-T92-B	DTA123EG-T92-B	TO-92	G	O	I	Tape Box
DTA123EL-T92-R	DTA123EG-T92-R	TO-92	G	O	I	Tape Reel

<p>DTA123EL-AE3-R</p> <p>(1)Packing Type (2)Package Type (3)Lead Plating</p>	<p>(1) B: Tape Box, K: Bluk, R: Tape Reel (2) AE3: SOT-23, AL3: SOT-323, AN3: SOT-523 T92: TO-92 (3) L: Lead Free , G: Halogen Free</p>
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■ MARKING



For SOT-23/SOT-323/SOT-523

■ ABSOLUTE MAXIMUM RATINGS (T_A=25°C)

PARAMETER		SYMBOL	RATINGS	UNIT
Supply Voltage		V _{CC}	-50	V
Input Voltage		V _{IN}	-12 ~ +10	V
Output Current		I _{OUT}	-100	mA
Power Dissipation	SOT-523	P _D	150	mW
	SOT-23/SOT-323		200	mW
	TO-92		625	mW
Junction Temperature		T _J	+150	°C
Storage Temperature		T _{STG}	-55 ~ +150	°C

Note Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

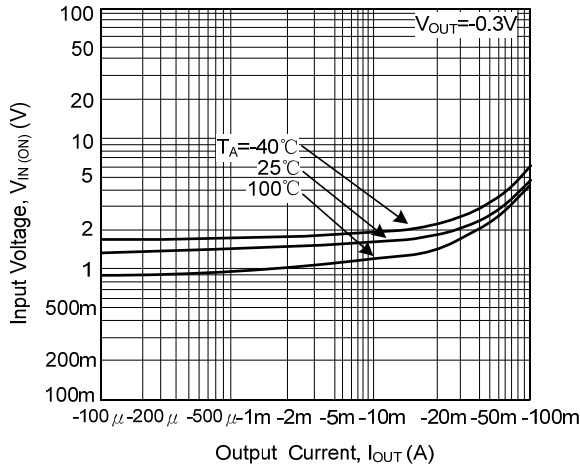
■ ELECTRICAL SPECIFICATIONS (T_A=25°C)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Input Voltage	V _{IN(OFF)}	V _{CC} = -5V, I _{OUT} = -100μA			-0.5	V
	V _{IN(ON)}	V _{OUT} = -0.3V, I _{OUT} = -20mA	-3			
Output Voltage	V _{OUT(ON)}	I _{OUT} /I _{IN} = 10mA/-0.5mA		-0.1	-0.3	V
Input Current	I _{IN}	V _{IN} = -5V			-3.8	mA
Output Current	I _{OUT(OFF)}	V _{CC} = -50V, V _{IN} = 0V			-0.5	μA
DC Current Gain	G _{IN}	V _{OUT} = -5V, I _{OUT} = -20mA	20			
Input Resistance	R ₁		1.54	2.2	2.86	KΩ
Resistance Ratio	R ₂ /R ₁		0.8	1	1.2	
Transition Frequency	f _T	V _{CE} = -10V, I _E = -5mA, f = 100MHz (Note)		250		MHz

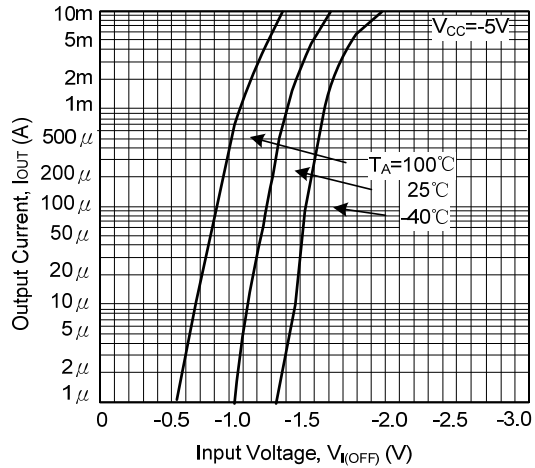
Note: Transition frequency of the device

■ TYPICAL CHARACTERISTIC

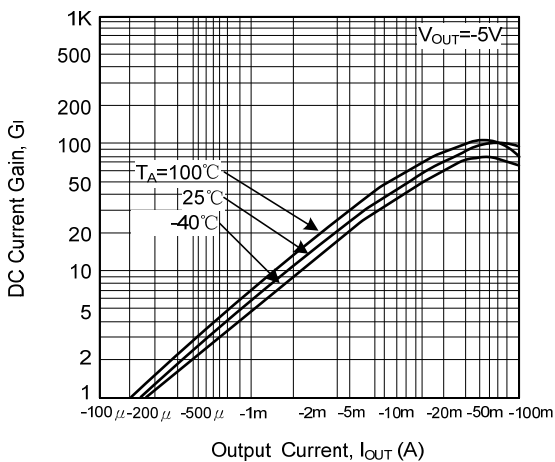
Input Voltage vs. Output Current
(ON Characteristics)



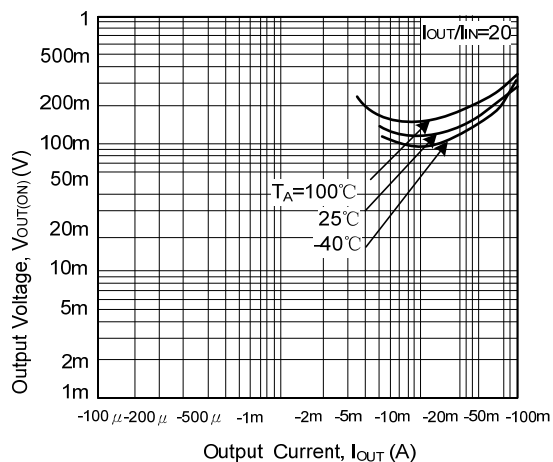
Output Current vs. Input Voltage
(OFF Characteristics)



DC Current Gain vs. Output Current



Output Voltage vs. Output Current



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